



## PJD60R620E / PJP60R620E / PJF60R620E

### 600V N-Channel Super Junction MOSFET

**Voltage**

**600 V**

**Current**

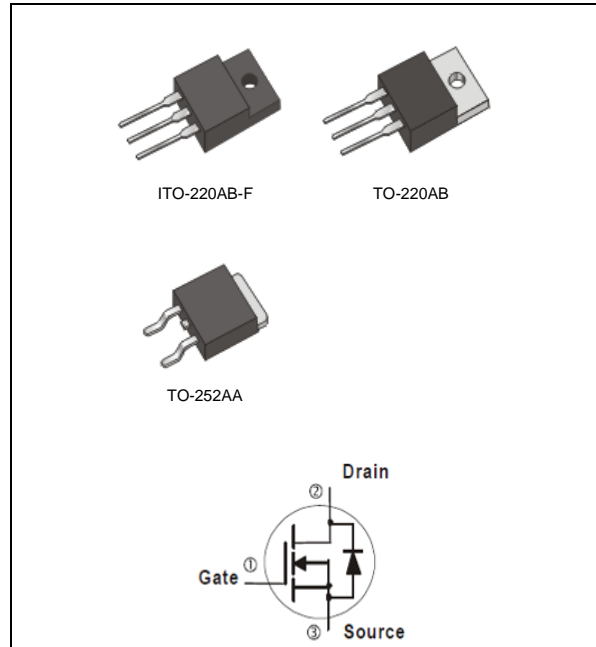
**7 A**

#### Features

- $R_{DS(ON)}, V_{GS}@10V, I_D@2.4A < 0.62\Omega$
- Fast switching speed
- Low on-resistance
- Low Noise
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### Mechanical Data

- Case : TO-252AA, TO-220AB, ITO-220AB-F
- Terminals : Solderable per MIL-STD-750, Method 2026
- TO-252AA Approx. Weight : 0.0104 ounces, 0.297grams
- TO-220AB Approx. Weight : 0.067 ounces, 1.89 grams
- ITO-220AB-F Approx. Weight : 0.068 ounces, 2 grams



#### Maximum Ratings and Thermal Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER		SYMBOL	TO-220AB	ITO-220AB-F	TO-252AA	UNITS
Drain-Source Voltage		$V_{DS}$	600			V
Gate-Source Voltage		$V_{GS}$	$\pm 20$			
Continuous Drain Current (Note 4)	$T_C=25^\circ\text{C}$	$I_D$	7			A
	$T_C=100^\circ\text{C}$		4.5			
Pulsed Drain Current (Note 1)		$I_{DM}$	14			
Power Dissipation (Note 3)	$T_C=25^\circ\text{C}$	$P_D$	78	45	78	W
	$T_C=100^\circ\text{C}$		31	18	31	
Continuous Drain Current (Note 4)	$T_A=25^\circ\text{C}$	$I_D$	1.2			A
	$T_A=70^\circ\text{C}$		0.9			
Power Dissipation	$T_A=25^\circ\text{C}$	$P_D$	2	1.04	2	W
	$T_A=70^\circ\text{C}$		1.3	0.9	1.3	
Single Pulse Avalanche Energy (Note 6)		$E_{AS}$	85			mJ
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~150			$^\circ\text{C}$
Typical Thermal Resistance (Note 4,5)		$R_{\theta JC}$	1.6	2.78	1.6	$^\circ\text{C/W}$
		$R_{\theta JA}$	62.5	120	62.5	

- Limited only By Maximum Junction Temperature



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### Electrical Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
<b>Static</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V, I_D=250\mu A$	600	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	2	2.9	4	
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=2.4A$	-	0.54	0.62	$\Omega$
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=600V, V_{GS}=0V$	-	-	1	$\mu A$
Gate-Source Leakage Current	$I_{GSS}$	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	$\pm 100$	nA
Diode Forward Voltage	$V_{SD}$	$I_S=7A, V_{GS}=0V$	-	0.95	1.5	V
Transconductance	$G_{FS}$	$V_{DS}=10V, I_D=3.5A$	-	3.8	-	S
<b>Dynamic</b> (Note 7)						
Total Gate Charge	$Q_g$	$V_{DS}=300V, I_D=7A,$ $V_{GS}=10V$ (Note 2,3)	-	21	-	nC
Gate-Source Charge	$Q_{gs}$		-	3	-	
Gate-Drain Charge	$Q_{gd}$		-	11	-	
Gate Input Resistance	$R_g$	$F = 1\text{MHz}$	-	11.5	-	$\Omega$
Input Capacitance	$C_{iss}$	$V_{DS}=25V, V_{GS}=0V,$ $f=1\text{MHz}$	-	457	-	$\mu F$
Output Capacitance	$C_{oss}$		-	457	-	
Reverse Transfer Capacitance	$C_{rss}$		-	62	-	
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=300V, I_D=3.5A,$ $R_G=10\Omega$ (Note 2,3)	-	10	-	ns
Turn-On Rise Time	$t_r$		-	25	-	
Turn-Off Delay Time	$t_{d(off)}$		-	65	-	
Turn-Off Fall Time	$t_f$		-	26	-	
<b>Drain-Source Diode</b>						
Maximum Continuous Drain-Source Diode Forward Current	$I_S$	---	-	-	7	A
Maximum Pulsed Drain-Source Diode Forward Current	$I_{SM}$	---	-	-	14	
Reverse Recovery Time	$t_{rr}$	$V_{GS}=0V, I_S=7A$	-	269	-	ns
Reverse Recovery Charge	$Q_{rr}$	$di_f/dt=100A/\mu s$ (Note 2)	-	2.41	-	$\mu C$

**NOTES :**

1. Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$ .
2. Essentially independent of operating temperature typical characteristics.
3. Repetitive rating, pulse width limited by junction temperature  $T_{J(MAX)}=150^\circ\text{C}$ . Ratings are based on low frequency and duty cycles to keep initial  $T_J=25^\circ\text{C}$ .
4. The maximum current rating is package limited.
5. TO-252AA mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
6.  $L=100\text{mH}, I_{AS}=1.3A, V_{DD}=50V, R_G=25\text{ohm}$ , Starting  $T_J=25^\circ\text{C}$ .
7. Guaranteed by design, not subject to production testing.



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## TYPICAL CHARACTERISTIC CURVES

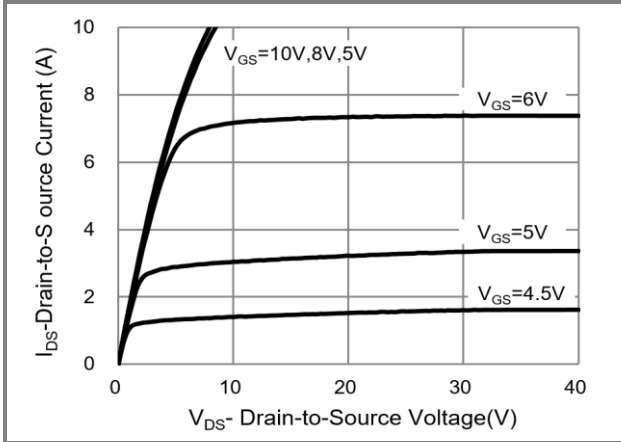


Fig.1 Output Characteristics

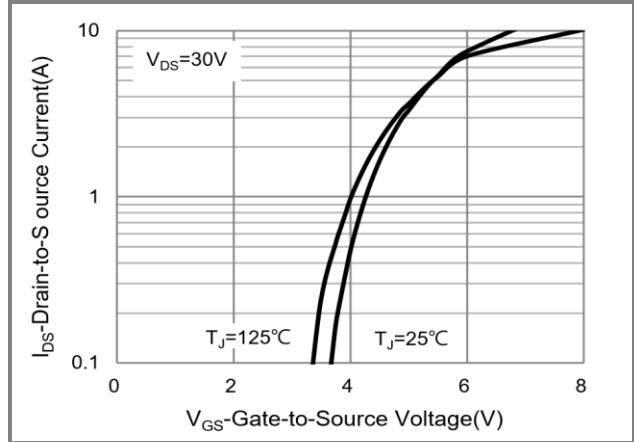


Fig.2 Transfer Characteristics

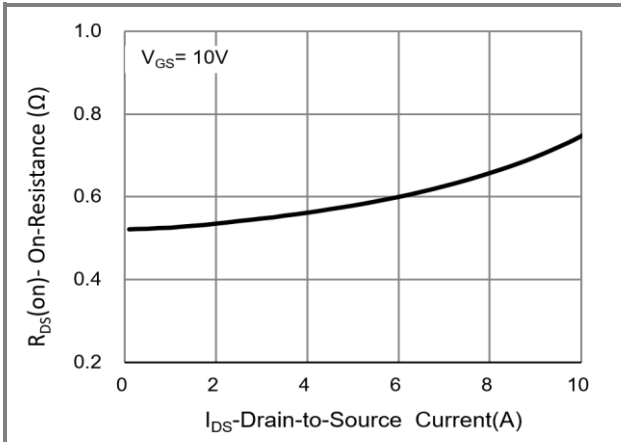


Fig.3 On-Resistance vs. Drain Current

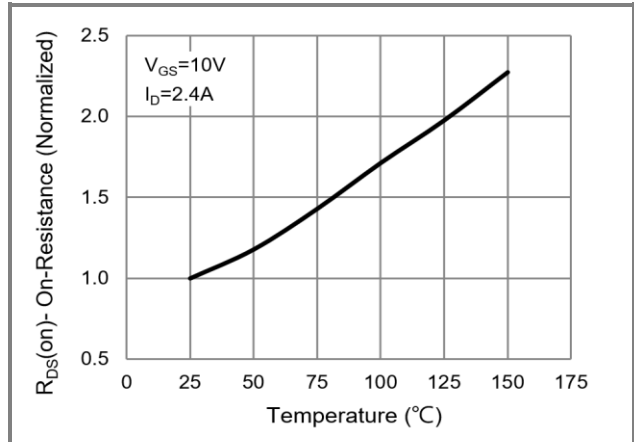


Fig.4 On-Resistance vs. Junction Temperature

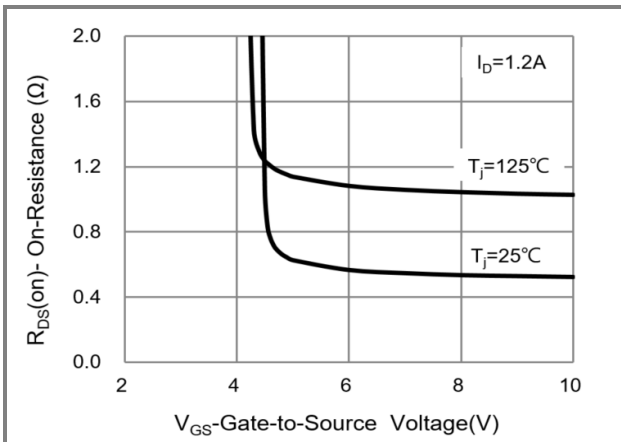


Fig.5 On-Resistance Variation with VGS

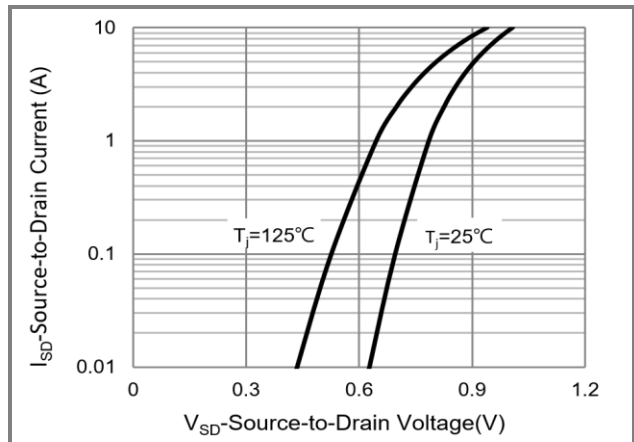
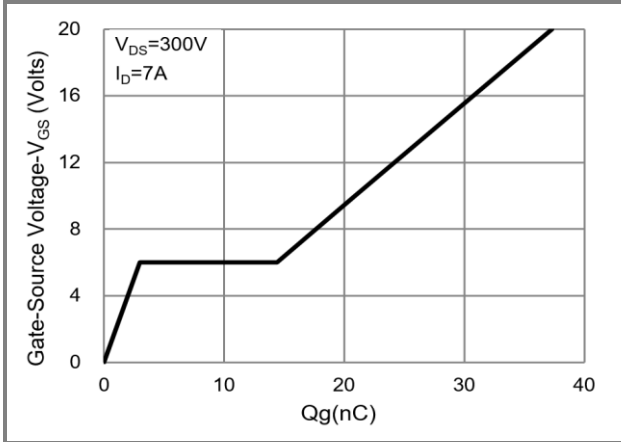


Fig.6 Source-Drain Diode Forward Voltage

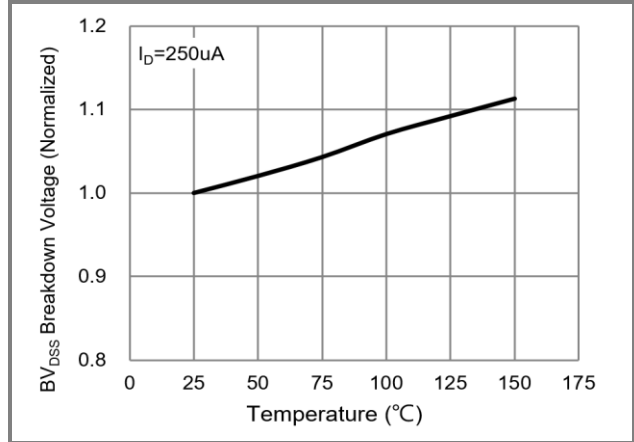


# PJD60R620E / PJP60R620E / PJF60R620E

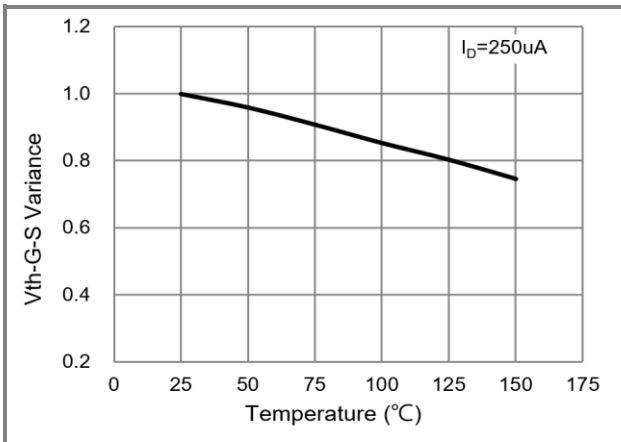
## TYPICAL CHARACTERISTIC CURVES



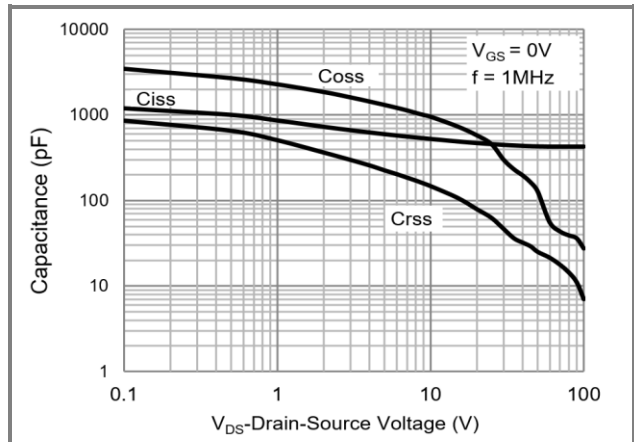
**Fig.7 Gate-Charge Characteristics**



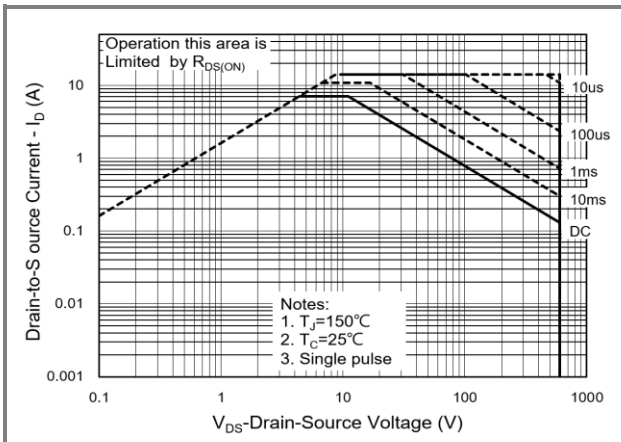
**Fig.8 Breakdown Voltage Variation vs. Temperature**



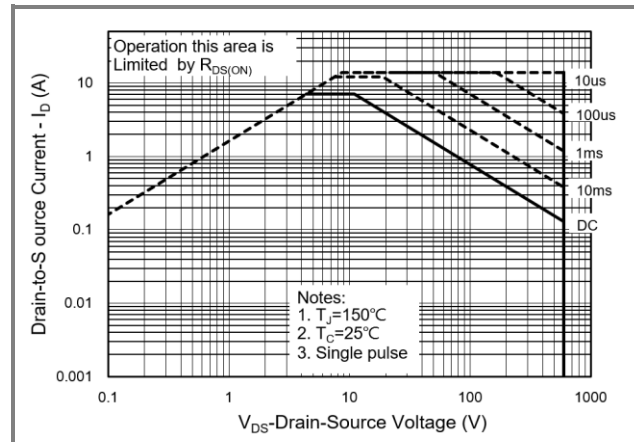
**Fig.9 Threshold Voltage Variation with Temperature**



**Fig.10 Capacitance vs. Drain-Source Voltage**



**Fig.11 PJD Maximum Safe Operating Area**



**Fig.12 PJP Maximum Safe Operating Area**



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## TYPICAL CHARACTERISTIC CURVES

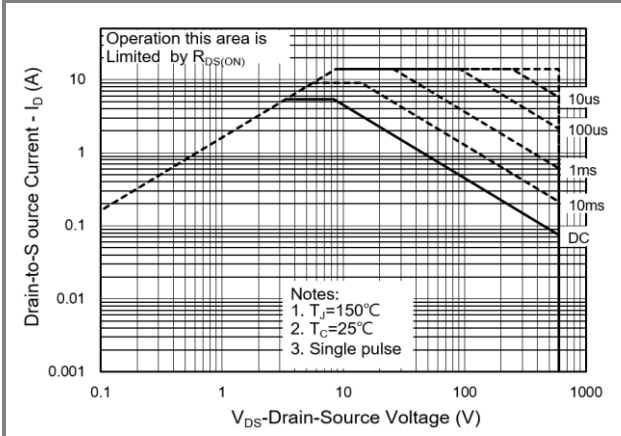


Fig.13 PJD Maximum Safe Operating Area

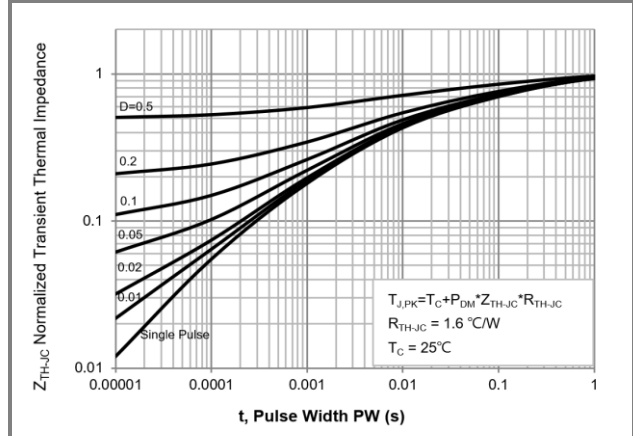


Fig.14 PJD Normalized Transient Thermal Impedance

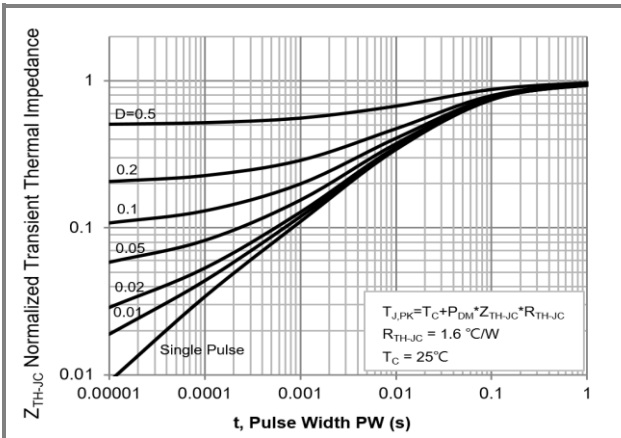


Fig.15 PJP Normalized Transient Thermal Impedance

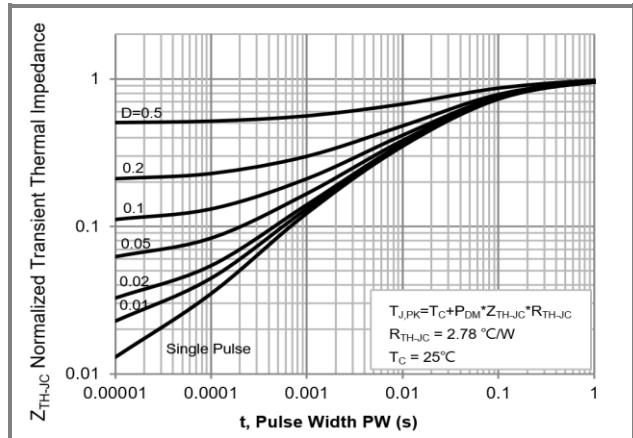


Fig.16 PJF Normalized Transient Thermal Impedance

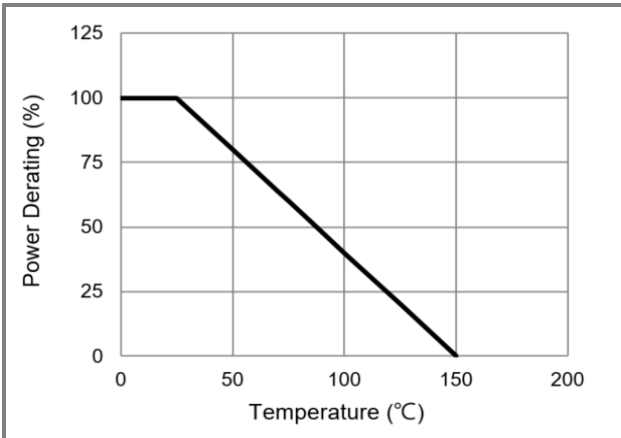
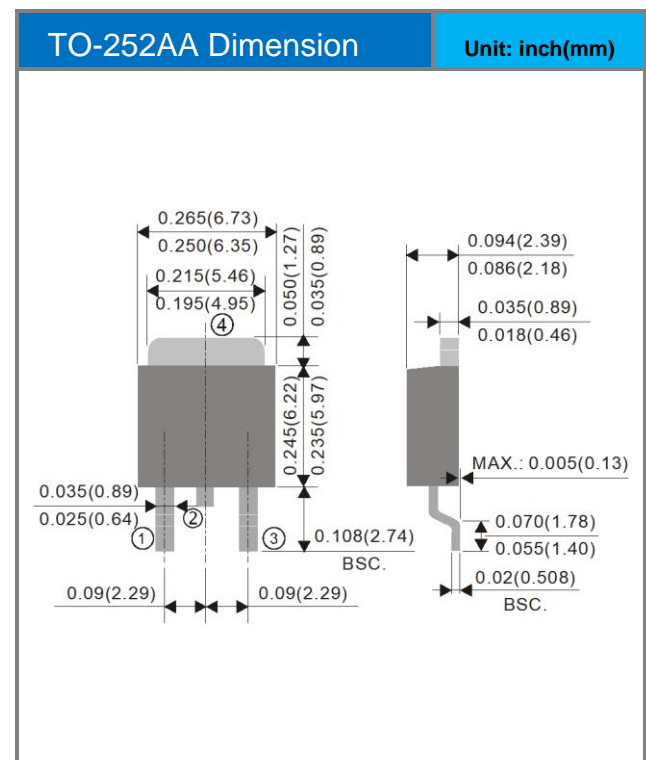
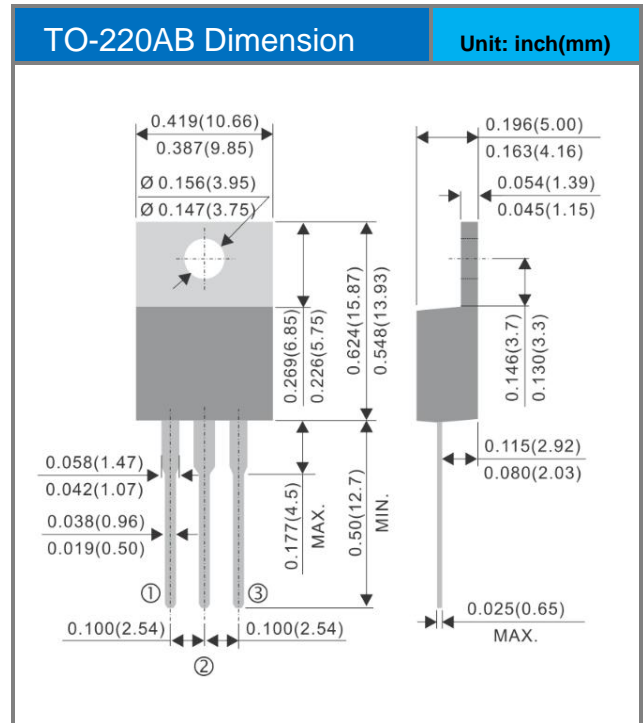
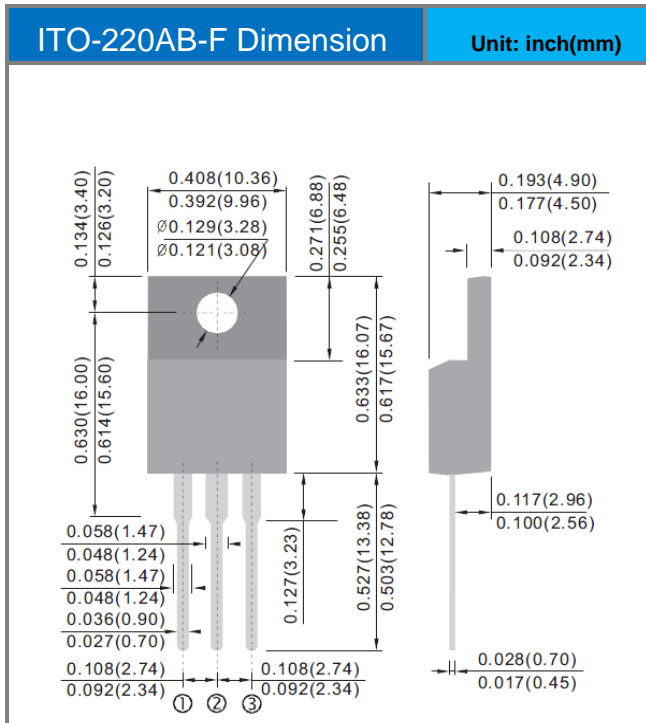


Fig.17 Total Power Dissipation



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## Packaging Information





## PJD60R620E / PJP60R620E / PJF60R620E

### Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJD60R620E_L2_00001	TO-252AA	3,000pcs / 13" reel	60R620E	Halogen free
PJP60R620E_T0_00001	TO-220AB	50pcs / Tube	60R620E	Halogen free
PJF60R620E_T0_00001	ITO-220AB-F	50pcs / Tube	60R620E	Halogen free



## **PJD60R620E / PJP60R620E / PJF60R620E**

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